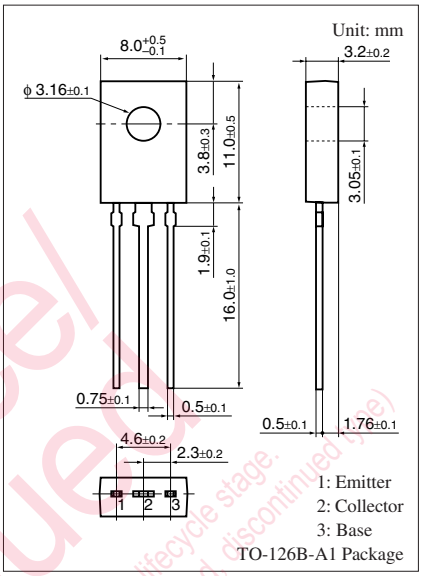
2SC1567, 2SC1567A

Silicon NPN epitaxial planar type

For low-frequency high power driver
Complementary to 2SA0794, 2SA0794A



■ Features

- High collector-emitter voltage (Base open) V_{CEO}
- Optimum for the driver stage of low-frequency and 40 W to 100 W output amplifier
- TO-126B package which requires no insulation plate for installation to the heat sink

■ Absolute Maximum Ratings $T_a = 25°C$

Parameter		Symbol	Rating	Unit
Collector-base voltage (Emitter open)	2SC1567	V_{CBO}	100	V
	2SC1567A		120	
Collector-emitter voltage (Base open)	2SC1567	V_{CEO}	100	V
	2SC1567A		120	
Emitter-base voltage (Collector open)		V_{EBO}	5	V
Collector current		I_C	0.5	A
Peak collector current		I_{CP}	1	A
Collector power dissipation		P_C	1.2	W
Junction temperature		T_j	150	°C
Storage temperature		T_{stg}	−55 to +150	°C

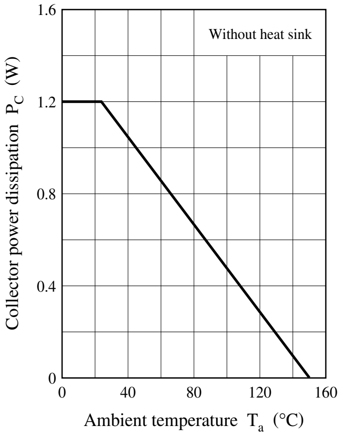
■ Electrical Characteristics $T_a = 25°C \pm 3°C$

Parameter		Symbol	Conditions	Min	Typ	Max	Unit
Collector-emitter voltage (Base open)	2SC1567	V_{CEO}	I_C = 100 µA, I_B = 0	100			V
	2SC1567A			120			
Emitter-base voltage (Collector open)		V_{EBO}	I_E = 1 µA, I_C = 0	5			V
Forward current transfer ratio		h_{FE1} *	V_{CE} = 10 V, I_C = 150 mA	130		330	—
		h_{FE2}	V_{CE} = 5 V, I_C = 500 mA	50	100		
Collector-emitter saturation voltage		$V_{CE(sat)}$	I_C = 500 mA, I_B = 50 mA		0.2	0.4	V
Base-emitter saturation voltage		$V_{BE(sat)}$	I_C = 500 mA, I_B = 50 mA		0.85	1.20	V
Transition frequency		f_T	V_{CB} = 10 V, I_E = −50 mA, f = 200 MHz		120		MHz
Collector output capacitance (Common base, input open circuited)		C_{ob}	V_{CB} = 10 V, I_E = 0, f = 1 MHz		11	20	pF

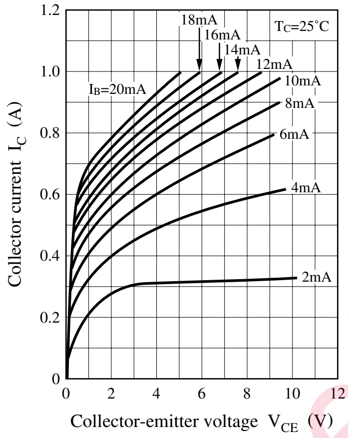
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.
2. *: Rank classification

Rank	R	S
h_{FE1}	130 to 220	185 to 330

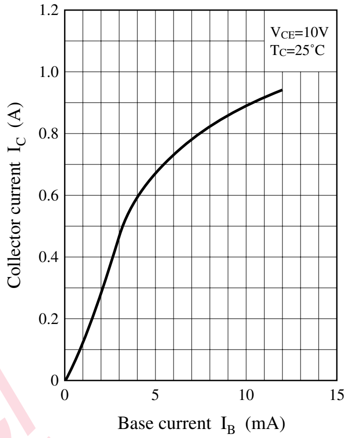
P_C — T_a



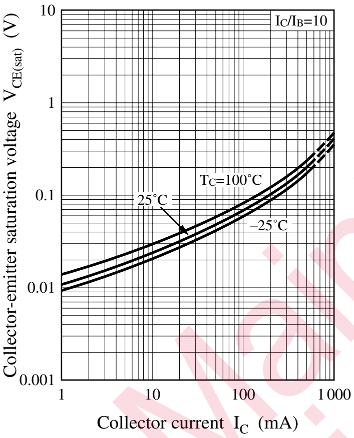
I_C — V_{CE}



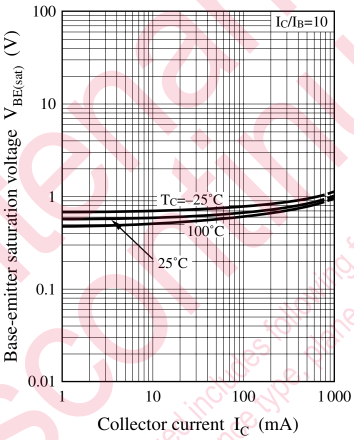
I_C — I_B



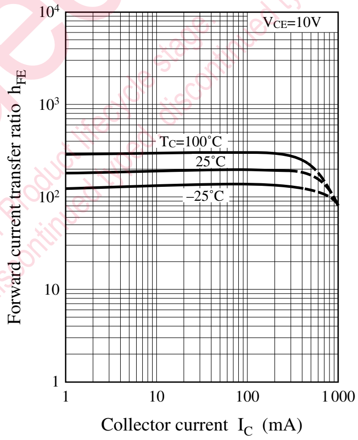
$V_{CE(sat)}$ — I_C



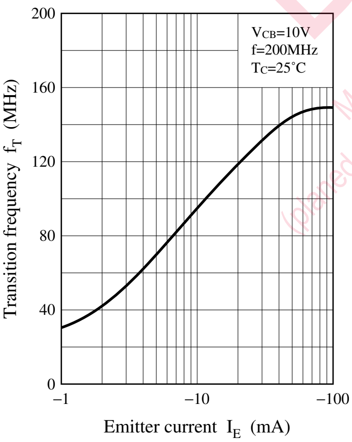
$V_{BE(sat)}$ — I_C



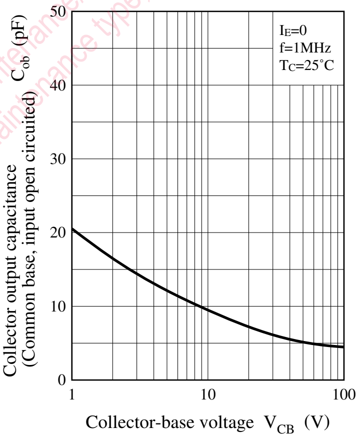
h_{FE} — I_C



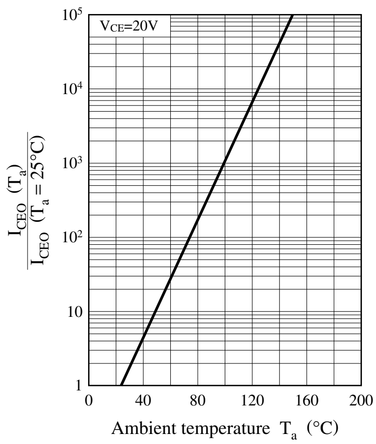
f_T — I_E



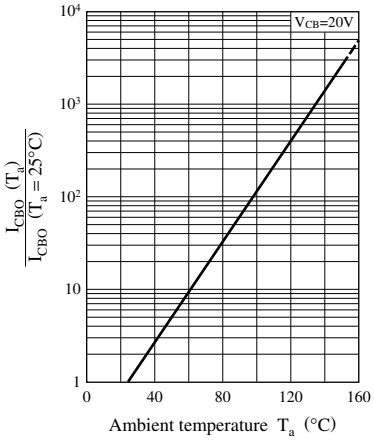
C_{ob} — V_{CB}



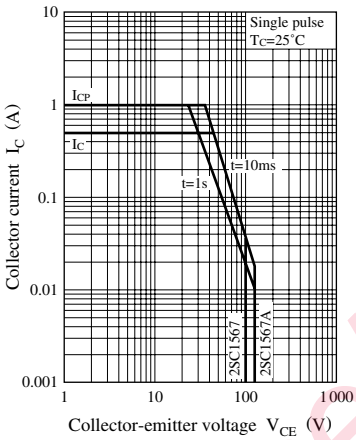
I_{CEO} — T_a



I_{CBO} — T_a



Safe operation area



Request for your special attention and precautions in using the technical information and semiconductors described in this book

(1) If any of the products or technical information described in this book is to be exported or provided to non-residents, the laws and regulations of the exporting country, especially, those with regard to security export control, must be observed.

(2) The technical information described in this book is intended only to show the main characteristics and application circuit examples of the products, and no license is granted under any intellectual property right or other right owned by our company or any other company. Therefore, no responsibility is assumed by our company as to the infringement upon any such right owned by any other company which may arise as a result of the use of technical information described in this book.

(3) The products described in this book are intended to be used for standard applications or general electronic equipment (such as office equipment, communications equipment, measuring instruments and household appliances).
Consult our sales staff in advance for information on the following applications:
- Special applications (such as for airplanes, aerospace, automobiles, traffic control equipment, combustion equipment, life support systems and safety devices) in which exceptional quality and reliability are required, or if the failure or malfunction of the products may directly jeopardize life or harm the human body.
- Any applications other than the standard applications intended.

(4) The products and product specifications described in this book are subject to change without notice for modification and/or improvement. At the final stage of your design, purchasing, or use of the products, therefore, ask for the most up-to-date Product Standards in advance to make sure that the latest specifications satisfy your requirements.

(5) When designing your equipment, comply with the range of absolute maximum rating and the guaranteed operating conditions (operating power supply voltage and operating environment etc.). Especially, please be careful not to exceed the range of absolute maximum rating on the transient state, such as power-on, power-off and mode-switching. Otherwise, we will not be liable for any defect which may arise later in your equipment.
 Even when the products are used within the guaranteed values, take into the consideration of incidence of break down and failure mode, possible to occur to semiconductor products. Measures on the systems such as redundant design, arresting the spread of fire or preventing glitch are recommended in order to prevent physical injury, fire, social damages, for example, by using the products.

(6) Comply with the instructions for use in order to prevent breakdown and characteristics change due to external factors (ESD, EOS, thermal stress and mechanical stress) at the time of handling, mounting or at customer's process. When using products for which damp-proof packing is required, satisfy the conditions, such as shelf life and the elapsed time since first opening the packages.